

ELECTRONICS AND TELECOMMUNICATION ENGINEERING**PAPER - I***Time Allowed : Three Hours**Maximum Marks : 200**Candidates should attempt question 1 which is compulsory and any FOUR of the remaining questions**The number of marks carried by each question is indicated at the end of the question*

1. (a) A rectangular wire mesh of infinite extent in a plane has 1 A of current fed into it at a point A, as shown below, and 1 A taken from it at point C. Find the current in the wire AC.

**Fig. Q. 1 (a)**

- 8
- (b) A conductor is charged by repeated contacts with a metal plate which, after each contact, is recharged to a quantity of charge Q . If q is the charge of the conductor after the first operation, what is the ultimate charge on the conductor?
- 8
- (c) Given two iron bars, identical in appearance, one magnetized, the other not. State how to distinguish them without using external magnetic fields. You are allowed to measure forces.
- 8
- (d) A flywheel of radius R , with charge Q uniformly distributed along its rim, rotates with angular velocity ω . What is the rate at which energy is radiated by the system?
- 8
- (e) The intrinsic resistivity of germanium at 300°K is 47 ohm-cm . What is its intrinsic carrier concentration? Also calculate the drift velocity of holes and of electrons for an electric field $E = 100 \text{ V/cm}$. Given : $\mu_n = 0.39 \text{ m}^2/\text{V sec}$ and $\mu_p = 0.19 \text{ m}^2/\text{V sec}$. (Electronic charge $e = 1.6 \times 10^{-19} \text{ C}$)
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- (f) The edges of a cube consist of equal resistors of resistance R , which are jointed at the corners. Let a battery be connected to two opposite corners of a face of the cube. What is the effective resistance?
- 8
- (g) A short current filament is $\lambda/10$ in length. Calculate the numerical value of its radiation resistance.
- 8
- (h) A 300-ohm transmission line is to feed 72-ohm antenna at 100 Mc . Design a suitable matching section for the transmission line to look into a 300-ohm load.

2. (a) In a full-wave rectifier the value of load resistance is 5000Ω . Each diode has idealized characteristics having slope corresponding to a resistance of 800Ω . Voltage applied to each diode has amplitude of 300 V and frequency equal to 50 Hz . Calculate (i) peak, average and r.m.s. values of current, (ii) d.c. power output and total power input, (iii) rectifier efficiency, (iv) form factor, and (v) ripple factor.

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- (b) A transistor in mid-frequency range is represented as shown below. Determine its h-parameters.



3. (a) The potential $\psi(x)$, satisfies Poisson's equation in the barrier region of p-n junction diode with a Schottky barrier. Take the positive x-direction from the p-region to the n-region through the junction $x = 0$ at the p-side of the transition region and $x = d$ on the n-side. Assume reasonable boundary conditions and calculate the width d , of the transition region, in terms of the donor and acceptor densities the dielectric coefficient ϵ , the diffusion potential V_d the applied potential V , and the electronic charge e . Show also that the capacitance per unit area of the junction is ϵ/d .

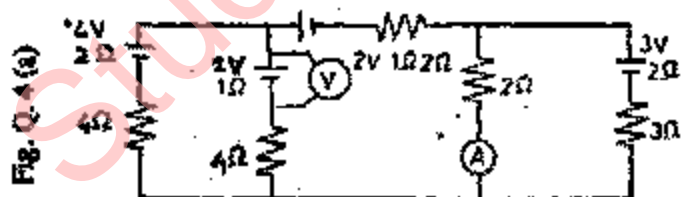
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- (b) A sample of germanium shows no Hall effect. If the mobility of electrons in germanium is $3500\text{ cm}^2/\text{V sec}$ and that of the holes is $1400\text{ cm}^2/\text{V sec}$, what fraction of the current in the sample is carried by electrons? Prove formula used.

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4. (a) Calculate the readings of ammeter A and voltmeter V in the circuit shown below. The voltmeter is assumed to have infinite resistance and the ammeter zero resistance.

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- (b) A thin dielectric rod of cross-section A extends along the x-axis from $x = 0$ to $x = L$. The polarization of the rod is along its length, and is given by $P_1 = ax^2 + b$. Find the volume density of polarization charge and the surface polarization charge on each end. Show explicitly that the total bound charge vanishes in this case.

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5. (a) Define a transducer. Give three examples of transducers involving different principles of action. A strain gauge has a gain factor of 4. If this strain gauge is attached to a metal bar that stretches from 25 cm to 25.2 cm , calculate the percentage change in its resistance. If the unstrained value of resistance is 120Ω , what would be its value after strain is applied?

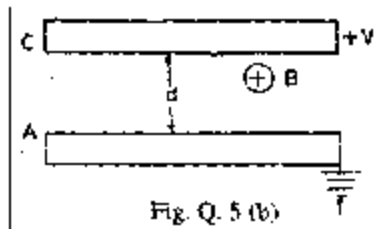
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- (b) Electrons emitted from a surface A, as shown below, are accelerated toward surface C which is maintained at a potential of +V volts. The separation of the plates is d metre. Show that the value of the flux density B at which current will cease to flow to plate C is given by

$$B = 2mV / ed^2$$

where m and e are electronic mass and charge respectively.

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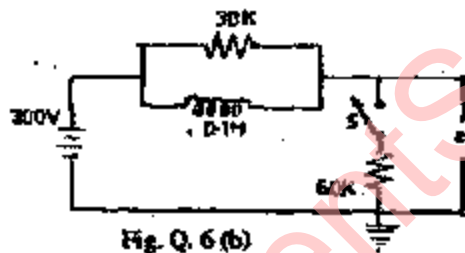


6. (a) Design a constant K low pass T and π -section filters to be terminated in 600Ω , having cut-off frequency 3kHz. Also determine (i) the frequency at which the filters offer attenuation of 17.372 dB and (ii) the characteristic impedance and phase constant at 2kHz.

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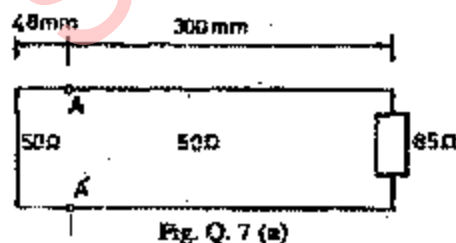
- (b) The switch S, as shown below, remains open for a long time before it is closed at $t = t_0$ for 50μ sec. It is then opened. Calculate the output voltage e_o at $t = t_0$ and at $t = 50\mu$ sec.

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7. (a) A lossless transmission line of characteristic impedance 50Ω is terminated at one end in a short-circuit and at the other end in a resistive impedance of 85Ω as shown below. The impedance measured at the junction AA' is found to be 75Ω resistive, at a frequency of 44 MHz. Calculate the phase velocity in the transmission line.

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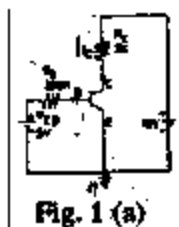


- (b) A parallel plate capacitor consists of two metal plates of area A and separation d. A slab of thickness t, and dielectric constant ϵ is inserted between the plates with its faces parallel to the plates and having the same surface area as that of the plates. Find the capacitance of the system. If $\epsilon = 2$, for what value of t will the capacitance of the system be $3/2$ times that of the air-capacitor alone? If the charge Q in the capacitor remains unchanged, calculate the energy in the two cases and account for the change in energy.

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ELECTRONICS AND TELECOMMUNICATION ENGINEERING**PAPER - II***Time Allowed: Three Hours**Maximum Marks: 200**Candidates should attempt any FIVE Questions choosing at least**TWO from each section**The number of marks Lamed by each question is indicated at the end of the question.**Answers must be written in English.***SECTION A**

1. (a) Find the transistor currents in the circuit of Fig. 1 (a). A silicon transistor with $\beta=100$ and $I_{co}=20 \text{ nA}$ is under consideration.



Repeat part a if a 2 K emitter resistor is added to the circuit as shown in Fig.(b).

Sketch the small signal high frequency circuit of a common source amplifier. Also, derive the expression for voltage gain

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- (b) Show that the trans-conductance g_m of a JFET is related to the drain current I_{DS} by

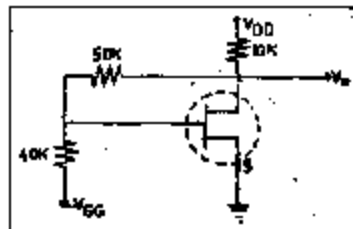
$$g_m = 2\sqrt{I_{DSS}I_{DS}} / |V_P|$$

where the symbols have their usual meaning. If $V_P = -4\text{V}$ and $I_{DSS} = 4 \text{ mA}$ plot g_m Versus I_{DS} For a p-channel silicon FET with $a = 2 \times 10^{-4} \text{ cm}$ and channel resistivity $\rho = 10 \Omega\text{-cm}$

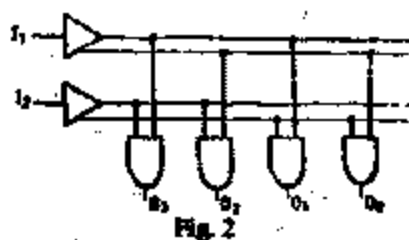
- find the pinch-off voltage;
- repeat (i) for a p-channel Ge FET with $\rho = 2 \Omega\text{-cm}$.

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- (c) Draw a CMOS inverter showing positive logic. Draw a MOSFET circuit satisfying the logic equation $Y = \overline{A + BC}$ where Y is the output corresponding to the three inputs A, B and C. 10
- (d) If an input signal V_1 is impressed- between gate and ground, find the amplification $A_0 = V_0 / V_1$. Apply Miller's theorem to the 50 K resistor. The PET parameters are $\mu = 30$ and $r_d = 5$ K. Neglect capacitances. 10



2. (a) How is a FET used as a VVR (voltage variable resistance)? Explain. 10
- (b) Draw the circuit of the emitter coupled Astable Multivibrator and explain its operation. 10
- (c) Draw the circuit of a Schmitt trigger (regenerative comparator) and explain its operation. Sketch its transfer characteristics and response to an arbitrary signal. 10
- (d) Explain with Circuit Schematic the operation of a 4-bit magnitude comparator. Show how one may sort an array of binary numbers. 10
3. (a) Discuss in detail, the working of full-adder logic circuit and extend your discussion to explain a binary adder, which can be used to add two binary numbers. 10
- (b) Draw the circuit diagram of a Master-slave J-K flip-flop using NAND gates. What is race-around condition? How is it eliminated in Master-slave J-K flip-flop? 10
- (c) Design a modulo 9 asynchronous counter using Master-slave J-K flip-flop? 10
- (d) Draw the circuit diagram of a bipolar or MOS difference amplifier. Derive an expression for the voltage gain of the amplifier. What is a current mirror? 10
4. (a) Develop the truth table for the decoder. 10



- (b) Explain the working of a R-2R DAC and show how R-2R DAC converts the binary word 1000100 to an analog output. Find the magnitude of the output, given $V_{ref} = 5.0$ V. 12
- (c) Assume that a floppy disk measures 3.5 inches in diameter and that 50 per cent of its surface area is usable for data storage. If individual cells require a surface area of 2 square units, what maximum number of eight-bit bytes can be stored on the disk? 10
- (d) Give the logic diagram of a 4-bit bidirectional universal shift register. Show how reset, shift left, shift right and parallel load operations may be carried out. 10

5. (a) A feedback control system is having a

$$G(s) = \frac{k(s+40)}{s(s+10)}$$

and the feedback transfer function is

$$H(s) = \frac{1}{s+20}$$

Determine the limiting values of k for stable system. If the gain is reduced to 50 per cent of previous value, calculate the phase margin and gain margin. 20

- (b) What are the different method of controlling the speed of a DC motor? Describe one method using SCRs and AC power supply. 12
- (c) List the steps in drawing root locus. 8

SECTION B

6. (a) Explain the process of 'Drift space bunching' and 'Reflector bunching' using Applegate diagrams. 10
- (b) Derive an expression for the electronic-tuning range in a Reflex Klystron Oscillator in terms of the Q of the cavity and Δ^0 the small variation in transit angle by varying the Reflector Voltage. 15
- (c) In an experiment for the measurement of Reflex Klystron mode characteristics, the following data is obtained:

$V_0 = 300$ volts (Beam voltage); $V_{R1} = -143$ volts;

$V_{R2} = -105$ volts; $V_{R3} = -65$ volts.

The frequency of operations at the three reflector voltages given above was the same. Evaluate the actual operating mode numbers N_1 , N_2 and N_3 . 15

7. (a) Describe the different tones used in an automatic telephone exchange. 10

- (b) Design a cylindrical cavity resonator for use it a parametric amplifier to have the following specifications:

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Resonant Frequency GHz	Mode of Operation	U_{mm}
2.80	TE ₀₁₁	$3.832 = u'_{01}$
9.40	TE ₁₁₄	$1.841 = u'_{11}$

- (c) A lossless transmission line of $Z_p = 50$ ohms is terminated by a load $Z_L = 100 + j 100$. Using Smith's change, design a single stub matching arrangement to match the load to the Generator and the line. Calculate the position of the short circuited stub and the length of the stub for matching.
- (d) Show the trunking diagram of a 5 digit automatic exchange using stronger system and explain the terms 'Full availability' and 'Grade of Service'.

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8. (a) Explain the operation of a typical TV Camera using a Vidicon tube.

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- (b) Explain how the sound and picture signals are separated from the Composite Video Signal in the TV receiver. Give the details of the frequencies used in this connection.

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- (c) Explain the principle and working of a GUNN oscillator.

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- (d) An MT₁ Radar operates at 10 GHz with PRF of 3000 PPS. Calculate the lowest three blind speeds of this radar.

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9. (a) Explain with a neat schematic the working of a DPCM system. Compare the advantages and the disadvantages of DPCM with that of PCM.

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- (b) State and explain Hartley-Shannon Theorem. Calculate the, amount of information needed to open a lock whose combination consists of three numbers each ranging from 00 to 90.

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- (c) Give the schematic of a Magic-T used in microwave measurements and explain its working. Mention its uses.

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- (d) Write a note on microwave solid state devices for (i) low noise amplification and (ii) high power amplification.

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10. Write short notes on any four:

10×4

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|---|----------------------------|
| (a) Phase Locked Loop and its application | (c) Magnetrons |
| (b) Decca and Navigational aids | (e) A/D and D/A Converters |
| (d) Satellite Communication | (g) FDMA and TDMA. |
| (f) Microwave Antennas | |